

V _{CES}	650V
I _{C(100°C)}	80A
V _{CE(sat) (Typ.)}	1.5V
P _D	404W

Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching & Low Switching Loss
- 3) Short Circuit Withstand Time 2µs
- 4) Pb free Lead Plating ; RoHS Compliant

Applications

Solar Inverter

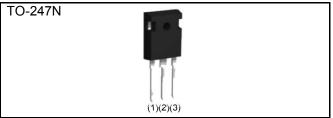
UPS

Welding

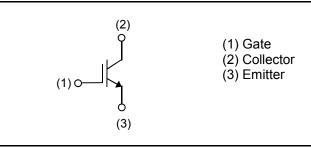
IH

PFC

Outline



Inner Circuit



Packaging Specifications

Туре	Packaging	Tube
	Reel Size (mm)	-
	Tape Width (mm)	-
	Basic Ordering Unit (pcs)	450
	Packing Code	C11
	Marking	RGTVX6TS65

•Absolute Maximum Ratings (at T_C = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V _{CES}	650	V
Gate - Emitter Voltage		V _{GES}	V _{GES} ±30	
Collector Current	$T_{\rm C}$ = 25°C	Ι _C	144	А
Collector Current	T _C = 100°C	Ι _C	80	А
Pulsed Collector Current		I _{CP} ^{*1}	320	А
Power Dissipation	$T_{\rm C}$ = 25°C	P _D	404	W
Power Dissipation	T _C = 100°C	P _D	202	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature		T _{stg}	–55 to +175	°C

*1 Pulse width limited by T_{imax.}

Thermal Resistance

Parameter	Symbol	Values			Unit
Parameter		Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.37	°C/W

•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit	
Faranielei	Symbol Conditions		Min.	Тур.	Max.	Unit	
Collector - Emitter Breakdown Voltage	BV _{CES}	I _C = 10μΑ, V _{GE} = 0V	650	-	-	V	
Collector Cut - off Current	I _{CES}	V _{CE} = 650V, V _{GE} = 0V	-	-	10	μA	
Gate - Emitter Leakage Current	I _{GES}	V _{GE} = ±30V, V _{CE} = 0V	-	-	±200	nA	
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	V _{CE} = 5V, I _C = 57.1mA	5.0	6.0	7.0	V	
Collector - Emitter Saturation Voltage	V _{CE(sat)}	I _C = 80A, V _{GE} = 15V T _j = 25°C T _j = 175°C	-	1.5 1.85	1.9 -	V	

•IGBT Electrical Characteristics (at $T_j = 25^{\circ}C$ unless otherwise specified)

Deremeter	Symbol	Conditions	Values			1.1
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	C _{ies}	V _{CE} = 30V	-	4810	-	
Output Capacitance	C _{oes}	V _{GE} = 0V	-	184	-	pF
Reverse Transfer Capacitance	C _{res}	f = 1MHz	-	79	-	
Total Gate Charge	Q_g	V _{CE} = 400V	-	171	-	
Gate - Emitter Charge	Q_{ge}	I _C = 80A	-	33	-	nC
Gate - Collector Charge	Q_{gc}	V _{GE} = 15V	-	59	-	
Turn - on Delay Time	t _{d(on)}	I _C = 80A, V _{CC} = 400V	-	45	-	
Rise Time	t _r	V_{GE} = 15V, R_{G} = 10 Ω	-	29	-	
Turn - off Delay Time	$t_{d(off)}$	T _j = 25°C	-	201	-	ns
Fall Time	t _f	Inductive Load	-	34	-	
Turn - on Switching Loss	E_{on}	*E _{on} includes diode	-	2.65	-	ml
Turn - off Switching Loss	E_{off}	reverse recovery	-	1.80	-	mJ
Turn - on Delay Time	t _{d(on)}	I _C = 80A, V _{CC} = 400V	-	49	-	
Rise Time	t _r	V_{GE} = 15V, R_G = 10 Ω	-	34	-	
Turn - off Delay Time	$t_{d(off)}$	T _j = 175°C	-	218	-	ns
Fall Time	t _f	Inductive Load	-	80	-	
Turn - on Switching Loss	Eon	*E _{on} includes diode	-	2.74	-	ml
Turn - off Switching Loss	E_{off}	reverse recovery	-	2.31	-	mJ
		I _C = 320A, V _{CC} = 520V				
Reverse Bias Safe Operating Area	RBSOA	V _P = 650V, V _{GE} = 15V	FU	LL SQUA	RE	-
		R _G = 100Ω, T _j = 175°C				
		$V_{CC} \leq 360V$				
Short Circuit Withstand Time	t _{sc}	V _{GE} = 15V	2	-	-	μs
		T _j = 25°C				

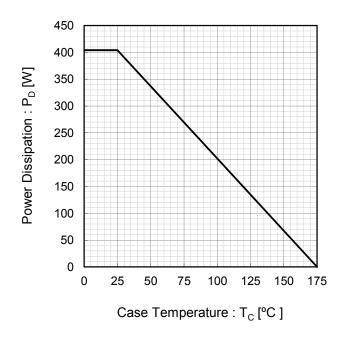


Fig.1 Power Dissipation vs. Case Temperature

Fig.2 Collector Current vs. Case Temperature

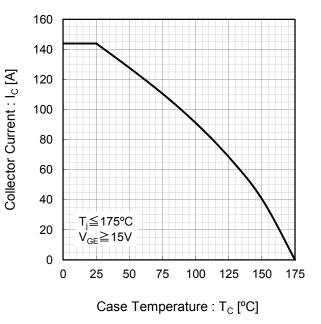
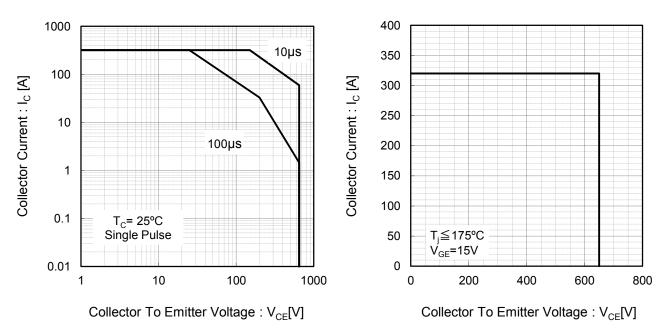


Fig.3 Forward Bias Safe Operating Area

Fig.4 Reverse Bias Safe Operating Area



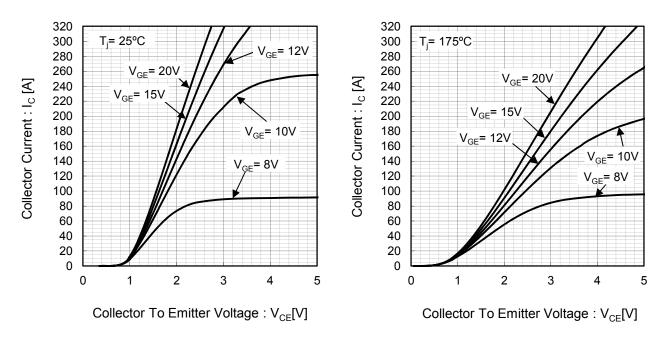


Fig.5 Typical Output Characteristics

Fig.7 Typical Transfer Characteristics Fig.8 Typical Collector

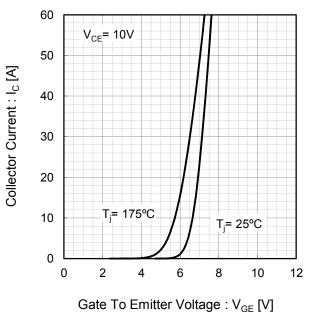


Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

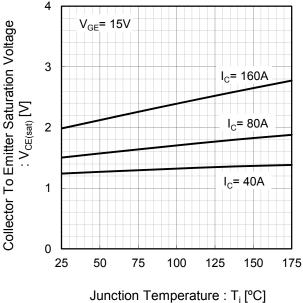


Fig.10 Typical Collector To Emitter Saturation Voltage

•Electrical Characteristic Curves

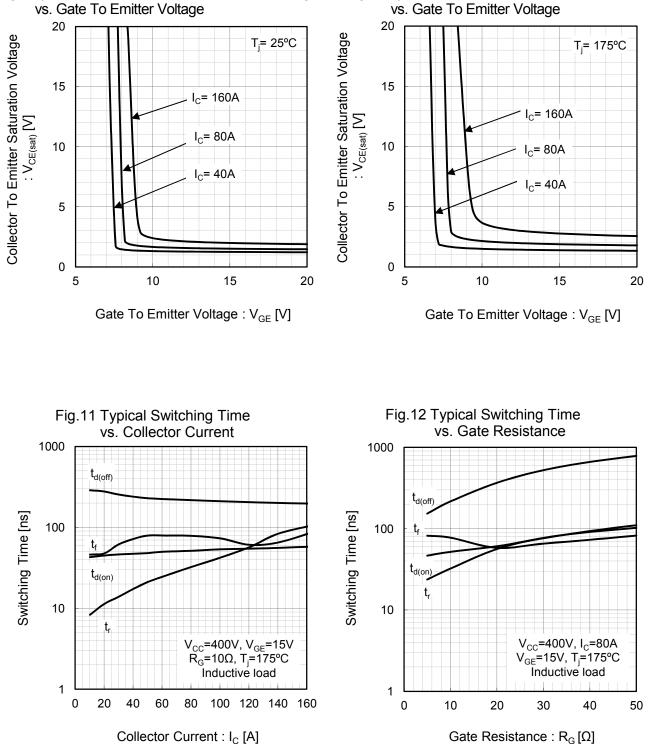
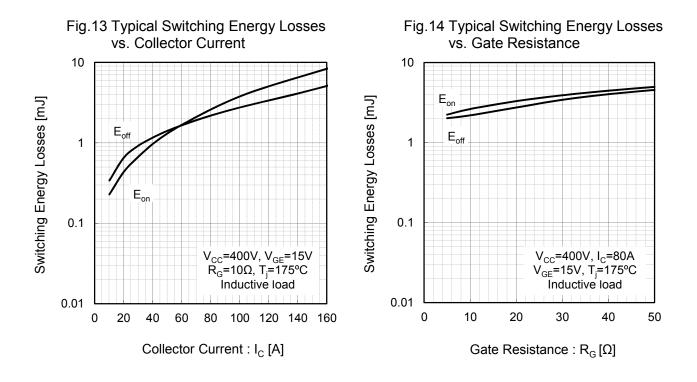


Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage



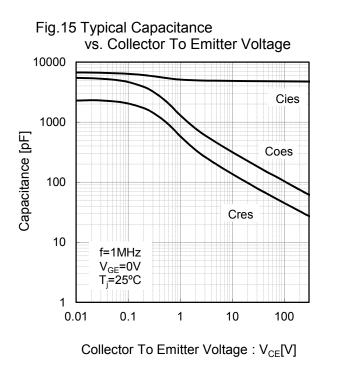
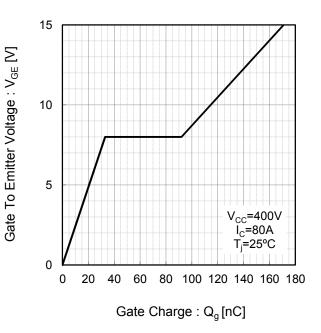
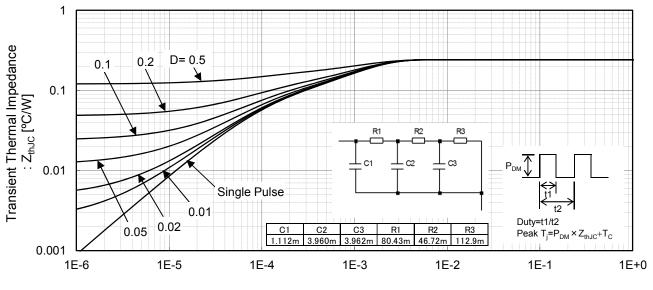
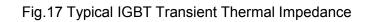


Fig.16 Typical Gate Charge

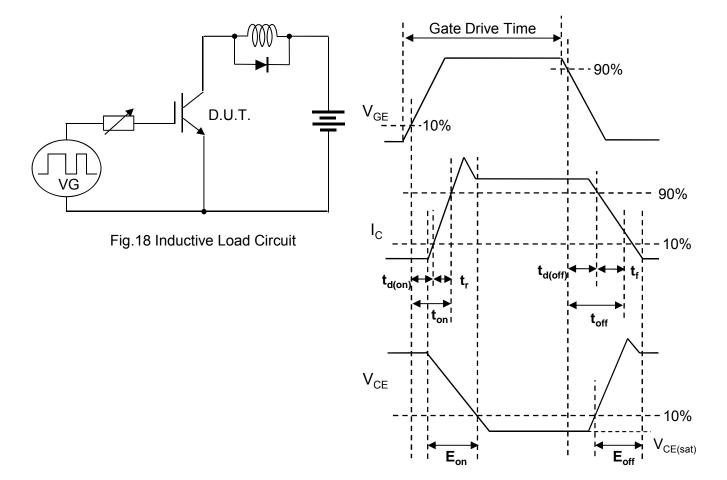






Pulse Width : t1[s]

●Inductive Load Switching Circuit and Waveform





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